

Product Features

- PI74ALVTC16827 is designed for low voltage operation, $V_{DD} = 1.65V$ to $3.6V$
- Supports Live Insertion
- 3.6V I/O Tolerant Inputs and Outputs
- Bus Hold
- High Drive, $-32/64mA @ 3.3V$
- Uses patented noise reduction circuitry
- Power-off high impedance inputs and outputs
- Industrial operation at $-40^{\circ}C$ to $+85^{\circ}C$
- Packages available:
 - 56-pin 240-mil wide plastic TSSOP (A56)
 - 56-pin 173-mil wide plastic TVSOP (K56)

Product Description

Pericom Semiconductor's PI74ALVTC series of logic circuits are produced using the Company's advanced 0.35 micron CMOS technology, achieving industry leading speed.

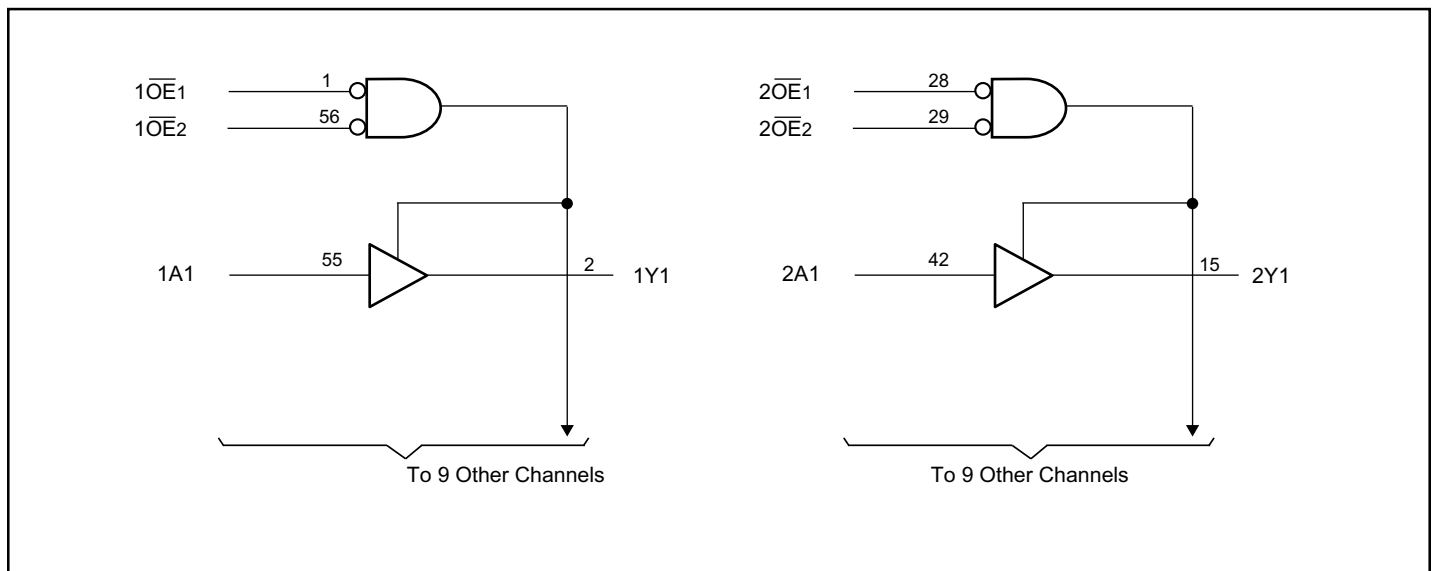
The PI74ALVTC16827, is a 20-Bit non-inverting buffer/driver designed for 1.65V to 3.6V V_{CC} operation.

A buffer/driver is composed of two 10-bit sections with separate output-enable signals. For either 10-Bit buffer section, the two output-enable ($1OE1$ and $1OE2$ or $2OE1$ and $2OE2$) inputs must both be low for the corresponding Y outputs to be active. If either output-enable input is HIGH, the output of that 10-Bit buffer section are in the high-impedance state.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor whose minimum value is determined by the current sinking capability of the driver.

The family offers both I/O Tolerant, which allows it to operate in mixed 1.65/3.6V systems, and "Bus Hold," which retains the data input's last state preventing "floating" inputs and eliminating the need for pullup/down resistors.

Logic Block Diagram



Product Pin Description

Pin Name	Description
$\overline{OE}$	Output Enable Inputs (Active LOW)
Ax	Data Inputs
Yx	3-State Outputs
GND	Ground
Vcc	Power

Truth Table⁽¹⁾

Inputs			Outputs
$\overline{OE1}$	$\overline{OE2}$	A	Y
L	L	L	L
L	L	H	H
H	X	X	Z
X	H	X	Z

Note:

- H = High Signal Level
L = Low Signal Level
X = Irrelevant
Z = High Impedance

Product Pin Configuration

$\overline{1OE1}$	1	56	$\overline{1OE2}$
1Y1	2	55	1A1
1Y2	3	54	1A2
GND	4	53	GND
1Y3	5	52	1A3
1Y4	6	51	1A4
VCC	7	50	VCC
1Y5	8	49	1A5
1Y6	9	48	1A6
1Y7	10	47	1A7
GND	11	46	GND
1Y8	12	45	1A8
1Y9	13	44	1A9
1Y10	14	43	1A10
2Y1	15	42	2A1
2Y2	16	41	2A2
2Y3	17	40	2A3
GND	18	39	GND
2Y4	19	38	2A4
2Y5	20	37	2A5
2Y6	21	36	2A6
VCC	22	35	VCC
2Y7	23	34	2A7
2Y8	24	33	2A8
GND	25	32	GND
2Y9	26	31	2A9
2Y10	27	30	2A10
2OE1	28	29	2OE2

56-pin
A, K

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Supply Voltage Range, V_{DD}	-0.5V to 4.6V
Input Voltage Range, V_I	-0.5V to 4.6V
Output Voltage Range, V_O (3-States)	-0.5V to 4.6V
Output Voltage Range, $V_O^{(1)}$ (Active)	-0.5V to $V_{DD}+0.5V$
DC Input Diode Current (I_{IK}) $V_I < 0V$	-50mA
DC Output Diode Current (I_{OK})	
$V_O < 0V$	-50mA
$V_O > V_{DD}$	±50mA
DC Output Source/Sink Current (I_{OH}/I_{OL})	-64/128mA
DC V_{DD} or GND Current per Supply Pin (I_{CC} or GND)	±100mA
Storage Temperature Range, T_{stg}	-65°C to 150°C

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions⁽²⁾

			Min.	Max.	Units
V_{DD}	Supply voltage	Operating	1.65	3.6	V
		Data Retention Only	1.2	3.6	
V_{IH}	High-level input voltage	$V_{DD} = 2.7V$ to 3.6V	2.0		
V_{IL}	Low-level input voltage	$V_{DD} = 2.7V$ to 3.6V		0.8	
V_I	Input voltage		-0.3	3.6	
V_O	Output voltage	Active State	0	V_{DD}	
		Off State	0	3.6	
	Output current in I_{OH}/I_{OL}	$V_{DD} = 3.0V$ to 3.6V $V_{DD} = 3.0V$ to 3.6V $V_{DD} = 2.3V$ to 2.7V $V_{DD} = 1.65V$ to 1.95V		-32/64 ±24 ±18 ±6	mA
$\Delta t/\Delta v$	Input transition rise or fall rate ⁽³⁾		0	10	ns/V
T_A	Operating free-air temperature		-40	85	°C

Notes:

1. Absolute maximum of I_O must be observed.
2. Unused control inputs must be held HIGH or LOW to prevent them from floating.
- 3 As measured between 0.8V and 2.0V, $V_{DD} = 3.0V$.

Electrical Characteristics over Recommended Operating Free-Air Temperature Range

(unless otherwise noted)

DC Characteristics (2.7V < V_{DD} ≤ 3.6V)

	Parameter	Conditions	V _{DD}	Min.	Typ.	Max.	Units
V _{IK}	Input Clamp Diode	I _{IK} = -18mA	3.0			-1.2	V
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100μA	2.7 - 3.6	V _{DD} - 0.2			
		I _{OH} = -12mA	2.7	2.2			
		I _{OH} = -18mA	3.0	2.4			
		I _{OH} = -24mA		2.2			
		I _{OH} = -32mA		2.0			
V _{OL}	LOW Level Output Voltage	I _{OL} = 100μA	2.7 - 3.6			0.2	
		I _{OL} = 12mA	2.7			0.4	
		I _{OL} = 18mA	3.0			0.4	
		I _{OL} = 24mA				0.45	
		I _{OL} = 32mA				0.5	
		I _{OL} = 64mA				0.55	
I _I	Input Leakage Current	V _I = V _{DD} , or GND	3.6			±5.0	μA
I _{OZ}	3-State Output Leakage	V _O = 3.6V	2.7			±10	
I _{OFF}	Power-OFF Leakage Current	V _I or V _O ≤ 3.6V	0			10	
I _{HOLD}	Bus Hold Current A or B Outputs	V _I = 0.8V	3.0	75			
		V _I = 2.0V		-75			
		V _I = 0 to 3.6V	3.6			±500	
I _{DD}	Quiescent Supply Current	V _I = V _{DD} or GND	2.7 - 3.6			50	
		V _{DD} ≤ (V _I , V _O) ≤ 3.6V				±50	
ΔI _{DD}	Increase in I _{DD} per input	V _{IH} = V _{DD} - 0.6V, Other inputs at V _{DD} or Gnd				400	

Electrical Characteristics over Recommended Operating Free-Air Temperature Range

(unless otherwise noted; continued from previous page)

DC Characteristics ($2.3V \leq V_{DD} \leq 2.7V$)

Description	Parameters	Conditions	V_{DD}	Min.	Typ.	Max.	Units
V_{IK}	Input Clamp Diode	$I_{IK} = -18mA$	2.3			-1.2	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\mu A$	2.3 -2.7	$V_{DD} - 0.2$			
		$I_{OH} = -12mA$	2.3	1.8			
		$I_{OH} = -18mA$		1.7			
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\mu A$	2.3 - 2.7			0.2	
		$I_{OL} = 12mA$	2.3			0.4	
		$I_{OL} = 18mA$				0.5	
		$I_{OL} = 24mA$				0.55	
I_I	Input Leakage Current	$V_I = V_{DD}$ or GND	2.7			± 5.0	μA
I_{OZ}	3-State Output Leakage	$V_O = 3.6V$	2.3			± 10	
I_{OFF}	Power-OFF Leakage Current	V_I or $V_O \leq 3.6V$	0			10	
$I_{HOLD}^{(1)}$	Bus Hold Current A or B Outputs	$V_I = 0.7V$	2.5		90		μA
		$V_I = 1.7V$			-90		
I_{DD}	Quiescent Supply Current	$V_I = V_{DD}$ or GND	2.3 - 2.7			40	
		$V_{DD} \leq (V_I, V_O) \leq 3.6V$				± 40	
ΔI_{DD}	Increase in I_{DD} per input	$V_{IH} = V_{DD} - 0.6V$, Inputs at V_{DD} or Gnd				400	

Note:

1. Not Guaranteed

Electrical Characteristics over Recommended Operating Free-Air Temperature Range

(unless otherwise noted; continued from previous page)

DC Characteristics ($1.65V \leq V_{DD} \leq 1.95V$)

Description	Parameters	Conditions	V_{DD}	Min.	Typ.	Max.	Units
V_{IK}	Input Clamp Diode	$I_{IK} = -18mA$	1.65			-1.2	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\mu A$	1.65-1.95	$V_{DD}-0.2$			
		$I_{OH} = -6mA$	1.65	1.4			
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\mu A$				0.2	
		$I_{OL} = 6mA$				0.3	
I_I	Input Leakage Current	$V_I = V_{DD}$ or GND	1.95			± 5.0	μA
I_{OZ}	3-State Output Leakage	$V_O = 3.6V$	1.65			± 10	
I_{OFF}	Power-OFF Leakage Current	$V_I = V_O \leq 3.6V$	0			10	
$I_{HOLD}^{(1)}$	Bus Hold Current A or B Outputs	$V_I = 0.4$	1.65		50		
		$V_I = 1.3$			-50		
I_{DD}	Quiescent Supply Current	$V_I = V_{DD}$ or GND	1.65-1.95			20	
		$V_{DD} \leq (V_I, V_O) \leq 3.6V$				± 20	
ΔI_{DD}	Increase in I_{DD} per input	$V_I = V_{DD} - 0.6V$, Other inputs at V_{DD} or Gnd				400	

Note:

1. Not Guaranteed

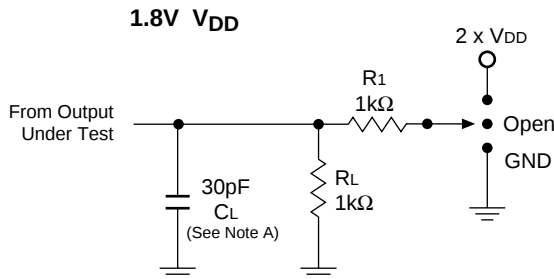
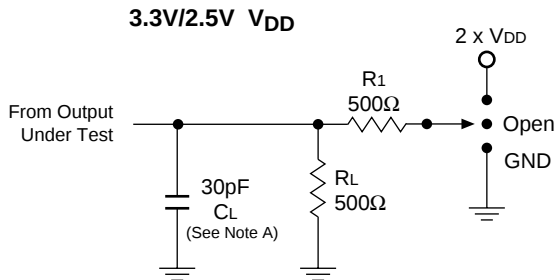
Switching Characteristics over recommended operating free-air temperature range

(unless otherwise noted, see Figures 1 thru 4)

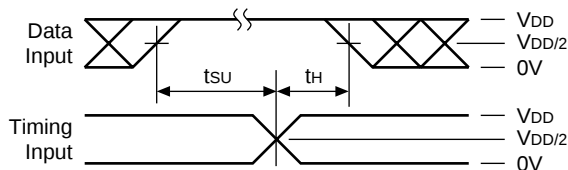
Parameters	From (Input)	To (Output)	$V_{CC} = 1.8V \pm 0.15V$		$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 3.3V \pm 0.3V$		Units
			Min.	Max.	Min.	Max.	Min.	Max.	
t_{pd}	A	Y		4.0	1.0	3.5	1.0	3.0	ns
t_{en}	$\overline{OE}$	Y		5.5	1.6	5.0	1.6	4.0	
t_{dis}	$\overline{OE}$	Y		5.5	2.2	5.0	2.2	4.0	

Test Circuits and Switching Waveforms

Parameter Measurement Information ($V_{DD} = 1.65V - 3.6V$)



Setup, Hold, and Release Timing



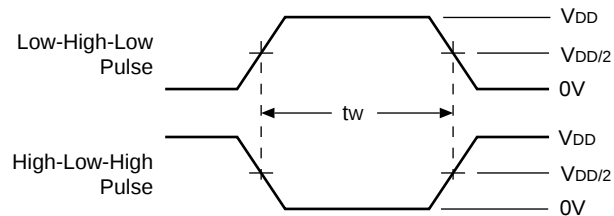
Notes:

- C_L includes probe and jig capacitance.
- Waveform 1 is for an output with internal conditions such that the output is LOW except when disabled by the output control.
Waveform 2 is for an output with internal conditions such that the output is HIGH except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50\Omega$, $t_r \leq 2\text{ns}$, $t_f \leq 2\text{ns}$, **measured from 10% to 90%, unless otherwise specified.**
- The outputs are measured one at a time with one transition per measurement.

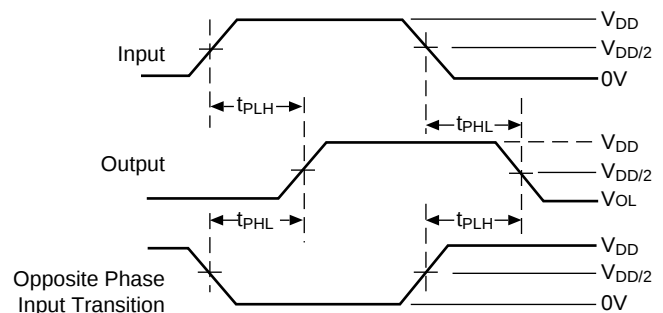
Switch Position

Test	S1
t_{PD}	Open
t_{PLZ}/t_{PZL}	$2 \times V_{DD}$
t_{PHZ}/t_{PZH}	GND

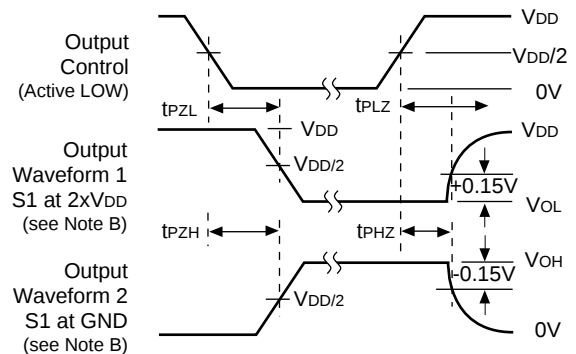
Pulse Width



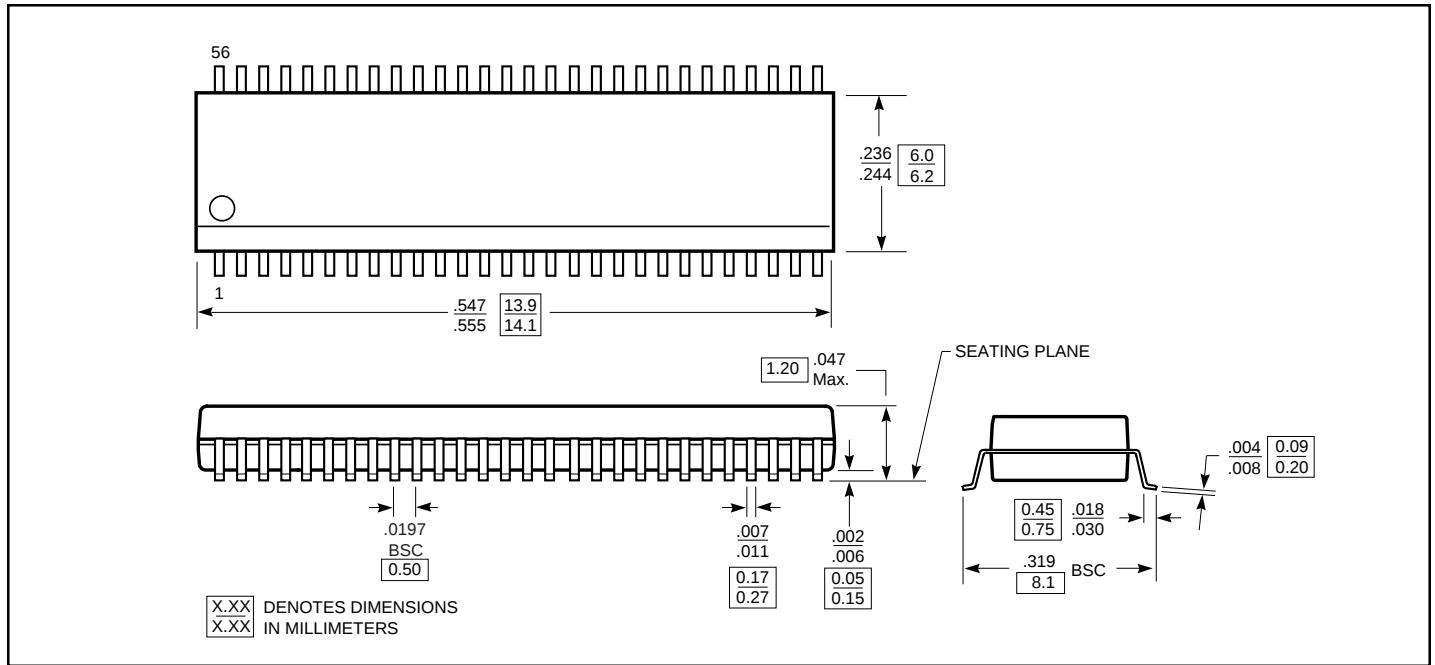
Propagation Delay



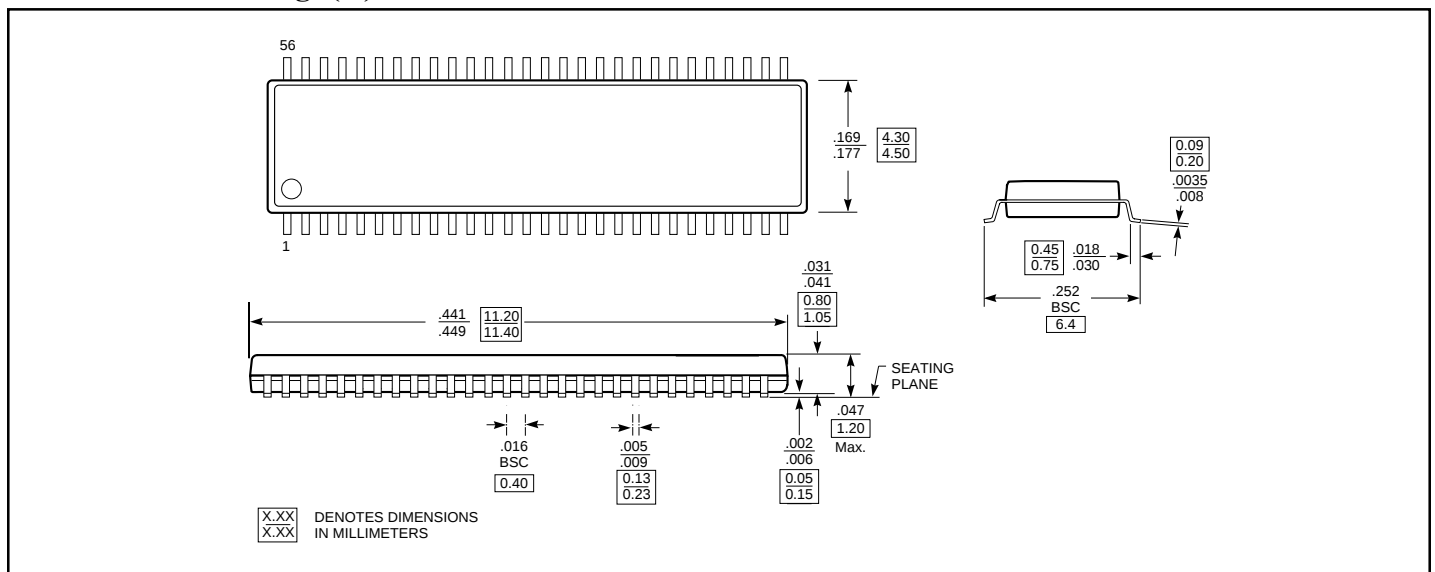
Enable/Disable Timing



56-Pin TSSOP Package (A)



56-Pin TVSOP Package (K)



Ordering Information

Ordering Code	Package Type	Ordering Range
PI74ALVTC16827A	56-Pin 240-mil TSSOP	-40°C to 85°C
PI74ALVTC16827K	56-Pin 173-mil TVSOP	